

## PART NUMBER 5413JR-ROCV

# Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

#### **Quality Overview**

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
  - Class Q Military
  - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

 Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



## SN5413, SN7413

### Dual 4-Input Positive-NAND Schmitt Triggers

Each circuit functions as a 4-input NAND gate, but because of the Schmitt action, it has different input threshold levels for positive  $(V_{T+})$  and for negative going  $(V_{T-})$  signals.

These circuits are temperature-compensated and can be triggered from the slowest of input ramps and still give clean, jitter-free output signals.

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DECEMBER 1983 - REVISED MARCH 1988

- Operation from Very Slow Edges
- Improved Line-Receiving Characteristics
- **High Noise Immunity**

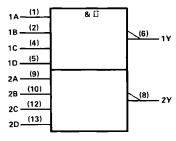
#### description

Each circuit functions as a 4-input NAND gate, but because of the Schmitt action, it has different input threshold levels for positive (VT+) and for negative going (V<sub>T</sub>\_) signals.

These circuits are temperature-compensated and can be triggered from the slowest of input ramps and still give clean, jitter-free output signals.

The SN5413 and SN54LS13 are characterized for operation over the full military temperature range of -55°C to 125°C. The SN7413 and SN74LS13 are characterized for operation from 0°C to 70°C.

#### logic symbol†



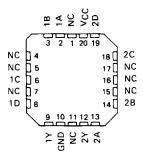
<sup>&</sup>lt;sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-13

Pin numbers shown are for D, J, N, and W packages.

SN5413, SN54LS13 . . . J OR W PACKAGE \$N7413 . . . N PACKAGE SN74LS13 . . . D OR N PACKAGE (TOP VIEW)

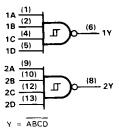
> 1А □ Т U 14□ VCC 13 2D 18 □ 12 2C NC  $\square^3$ 1C □4 11□ NC 10 2B 10 □5 9 2A 8 2Y 17 □6 GND □7

SN54LS13 . . . FK PACKAGE (TOP VIEW)



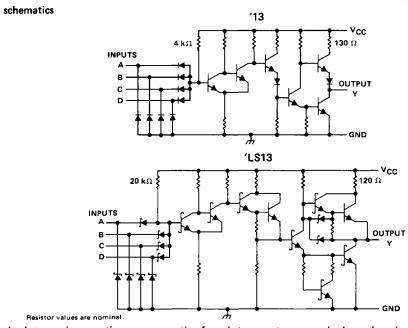
NC-No internal connection

#### logic diagram (positive logic)



PRODUCTION DATA documents cantain information current as of publication data. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.





absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note	1)	7 V
Input voltage: '13	.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	5.5 V
'L\$13	.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	7 V
Operating free-air temperature:	SN54'	- 55°C to 125°C
	SN74'	
Storage temperature range		– 65°C to 150°C

NOTE 1. Voltage values are with respect to network ground terminal.

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#### recommended operating conditions

			SN5413		SN7413			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNII
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
ІОН	High-level output current			- 0.8			- 0.8	mA
loL	Low-level output current			16			16	mA
TA	Operating free-air temperature	- 55		125	0		70	°C

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS <sup>†</sup>	MIN TYP\$ MAX	UNIT
V <sub>T+</sub>	V <sub>CC</sub> = 5 V	1.5 1.7 2	V
V <sub>T</sub> _	V <sub>CC</sub> = 5 V	0.6 0.9 1.1	V
Hysteresis (VT+ -VT)	V <sub>CC</sub> = 5 V	0.4 0.8	V
VIK	V <sub>CC</sub> = MIN, I <sub>I</sub> = - 12 mA	- 1.5	V
∨он	$V_{CC} = MIN$ , $V_{\parallel} = 0.6 \text{ V}$ , $I_{OH} = -0.8 \text{ mA}$	2.4 3.4	V
VOL	V <sub>CC</sub> = MIN, V <sub>I</sub> = 2 V, I <sub>OL</sub> = 16 mA	0 2 0.4	V
IT+	$V_{CC} = 5 V$ , $V_1 = V_{T+}$	- 0.65	mA
I <sub>T</sub> _	V <sub>CC</sub> = 5 V, V <sub>I</sub> = V <sub>T-</sub>	- 0.85	mA
I <sub>I</sub>	V <sub>CC</sub> = MAX, V <sub>I</sub> = 5.5 V	1	mΑ
Чн	V <sub>CC</sub> = MAX, V <sub>IH</sub> = 2.4 V	40	μА
III.	V <sub>CC</sub> = MAX, V <sub>IL</sub> = 0.4 V	- 1 - 1.6	mΑ
IOS §	V <sub>CC</sub> = MAX,	- 18 - 55	mA
ГССН	V <sub>CC</sub> = MAX	14 23	mΑ
ICCL	V <sub>CC</sub> = MAX	20 32	mA

 $<sup>^{\</sup>dagger}$  For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.  $^{\ddagger}$  All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C,  $_{\S}$  Not more than one output should be shorted at a time.

#### switching characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS			TYP	MAX	UNIT
tPLH	Any	>	$R_{\perp}$ = 400 $\Omega$ ,	C <sub>1</sub> = 15 pF		18	27	ns
tPHL_		· ·	11[ - 400 cz,	OL 10 P		15	22	ПS

#### recommended operating conditions

	Si	N54LS1	3	SN74LS13			
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V <sub>CC</sub> Supply voltage	4.5	5	5.5	4.75	5	5.25	V
IOH High-level output current			- 0.4			- 0.4	mA
OL Low-level output current			4		-	8	mA
TA Operating free-air temperatu	- 55		125	0		70	°C

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

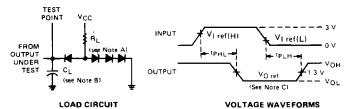
DADAMETER	TEST CONDITIONS <sup>†</sup>	SN54LS13		9	N74LS	13	
PARAMETER	LEST CONDITIONS.	MIN TYP# M	1AX	MIN	TYP‡	MAX	UNIT
V <sub>T+</sub>	V <sub>CC</sub> = 5 V	1,4 1,6	1.9	1.4	1.6	1.9	٧
ν <sub>T</sub>	V <sub>CC</sub> = 5 V	0.5 0.8	1	0,5	0.8	1	v
Hysteresis {VT+ -VT_1	V <sub>CC</sub> = 5 V	0.4 0.8		0.4	0.8		V
VIK	V <sub>CC</sub> = MIN, I <sub>1</sub> = -18 mA	_	1.5			- 1.5	V
Voн	V <sub>CC</sub> = MIN, V <sub>1</sub> = 0.5 V, I <sub>OH</sub> = + 0.4 mA	2.5 3.4		2.7	3.4		V
۷٥٢	V <sub>CC</sub> = MIN, V <sub>I</sub> = 1.9 V	0.25	0.4		0.25	0.4	17
, OL	I <sub>OL</sub> = 8 mA	<u></u> ,			0.35	0.5	V
I <sub>T+</sub>	$V_{CC} = 5 V$ , $V_I = V_{T+}$	- 0.14			- 0.14		mA
I <sub>T</sub>	V <sub>CC</sub> = 5 V, V <sub>1</sub> = V <sub>T</sub> _	- 0.18			- 0.18		mA _
ΙΙ	V <sub>CC</sub> = MAX, V <sub>1</sub> = 7 V		0.1			0.1	mΑ
ΊΗ	V <sub>CC</sub> = MAX, V <sub>IH</sub> = 2.7 V		20			20	μА
ηL	V <sub>CC</sub> = MAX. V <sub>IL</sub> = 0.4 V	-	0.4			- 0.4	mA
I <sub>OS</sub> q	V <sub>CC</sub> = MAX	- 20 -	100	- 20		- 100	mA
1ссн	V <sub>CC</sub> = MAX	2.9	6		2.9	6	mA
ICCL	V <sub>CC</sub> = MAX	4.1	7		4.1	7	mA

- † For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions
- All typical values are at V<sub>CC</sub> 5 v, T<sub>A</sub> = 25°C.
   Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

#### switching characteristics, $V_{CC}$ = 5 V , $T_{A}$ = $25^{\circ}C$

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	ТҮР	MAX	UNIT
<sup>t</sup> PLH	Anv	Y	R <sub>1</sub> ≈ 2 kΩ,	C <sub>1</sub> = 15 pF		15	22	ns
<sup>†</sup> PHL	1,			OL 19 PF		18	27	ns

#### PARAMETER MEASUREMENT INFORMATION



NOTES A. All diodes are 1N3064 or equivalent.

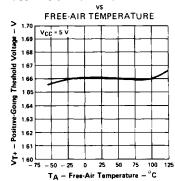
B CL includes probe and jig capacitance.

C. Generator characteristics and reference voltages are

	G	enerator C	haracteris	tics	Ref	erence Voltag	es
	Zout	PRR	t <sub>r</sub>	tf	VI ref(H)	VI ref(L)	VO ref
SN54'/SN74'	50 Ω	1 MHz	10 ns	10 ns	1.7 V	0.9 V	1,5 V
SN54LS'/SN74LS'	50 Ω	1 MHz	15 ns	6 ns	1.6 V	0.8 V	1.3 V

#### TYPICAL CHARACTERISTICS OF '13 CIRCUITS

POSITIVE GOING THRESHOLD VOLTAGE



NEGATIVE-GOING THRESHOLD VOLTAGE

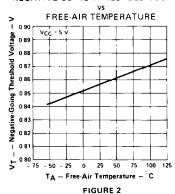


FIGURE 1

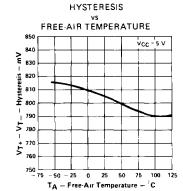


FIGURE 3

Data for temperatures below  $0^{\circ}$  C and  $70^{\circ}$  C and supply voltages below 4.75 V and above 5.25 V are applicable for SN5413 only.



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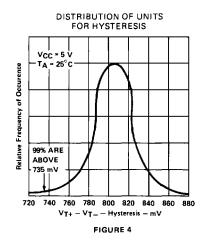
2-71

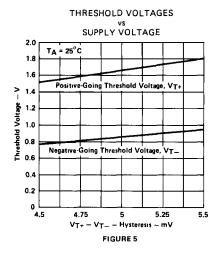
POST OFFICE BOX 655012 • DALLAS TEXAS 75265

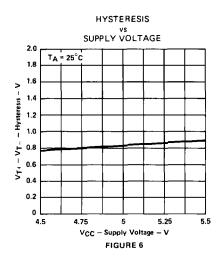
2

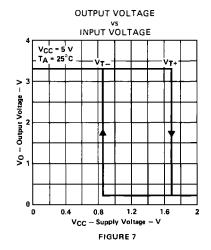
7L Devices

#### TYPICAL CHARACTERISTICS OF '13 CIRCUITS









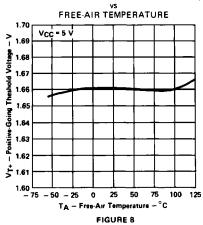
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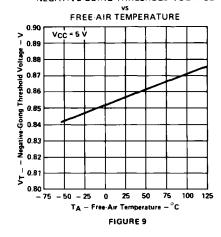
# TTL Devices N

#### TYPICAL CHARACTERISTICS OF 'LS13 CIRCUITS

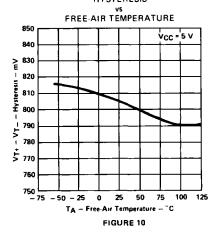




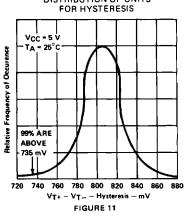
#### NEGATIVE GOING THRESHOLD VOLTAGE



#### HYSTERESIS



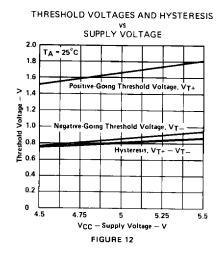
## DISTRIBUTION OF UNITS FOR HYSTERESIS

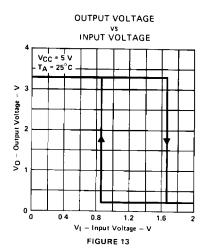


Data for temperatures below 0°C and above 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN54LS13 only.



#### TYPICAL CHARACTERISTICS OF 'LS13 CIRCUITS





Data for temperatures below 0°C and above 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN54LS13 only.

#### TYPICAL APPLICATION DATA

